

LM733/LM733C Differential Amplifier

General Description

The LM733/LM733C is a two-stage, differential input, differential output, wide-band video amplifier. The use of internal series-shunt feedback gives wide bandwidth with low phase distortion and high gain stability. Emitter-follower outputs provide a high current drive, low impedance capability. Its 120 MHz bandwidth and selectable gains of 10, 100 and 400, without need for frequency compensation, make it a very useful circuit for memory element drivers, pulse amplifiers, and wide band linear gain stages.

The LM733 is specified for operation over the -55°C to $+125^{\circ}\text{C}$ military temperature range. The LM733C is specified for operation over the 0°C to $+70^{\circ}\text{C}$ temperature range.

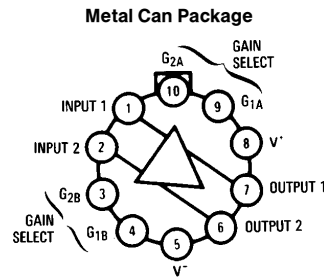
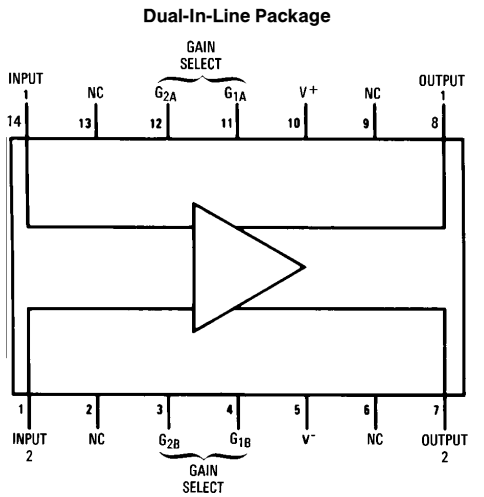
Features

- 120 MHz bandwidth
- 250 k Ω input resistance
- Selectable gains of 10, 100, 400
- No frequency compensation
- High common mode rejection ratio at high frequencies

Applications

- Magnetic tape systems
- Disk file memories
- Thin and thick film memories
- Woven and plated wire memories
- Wide band video amplifiers

Connection Diagrams



Note: Pin 5 connected to case.

Top View
Order Number LM733H or LM733CH
See NS Package Number H10D

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Differential Input Voltage	±5V
Common Mode Input Voltage	±6V
V _{CC}	±8V
Output Current	10 mA

Power Dissipation (Note 1)	500 mW
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range	
LM733	-55°C to +125°C
LM733C	0°C to +70°C
Lead Temperature (Soldering, 10 sec.)	260°C

Electrical Characteristics (T_A = 25°C, unless otherwise specified, see test circuits, V_S = ±6.0V)

Characteristics	Test Circuit	Test Conditions	LM733			LM733C			Units	
			Min	Typ	Max	Min	Typ	Max		
Differential Voltage Gain										
Gain 1 (Note 2)	1	R _L = 2 kΩ V _{OUT} = 3 Vp-p	300	400	500	250	400	600		
Gain 2 (Note 3)			90	100	110	80	100	120		
Gain 3 (Note 4)			9.0	10	11	8.0	10	12		
Bandwidth										
Gain 1	2			40			40		MHz	
Gain 2				90			90		MHz	
Gain 3				120			120		MHz	
Rise Time										
Gain 1	2	V _{OUT} = 1 Vp-p		10.5			10.5		ns	
Gain 2				4.5	10		4.5	12	ns	
Gain 3				2.5			2.5		ns	
Propagation Delay										
Gain 1	2	V _{OUT} = 1 Vp-p		7.5			7.5		ns	
Gain 2				6.0	10		6.0	10	ns	
Gain 3				3.6			3.6		ns	
Input Resistance										
Gain 1				4.0			4.0		kΩ	
Gain 2				20	30		10	30		kΩ
Gain 3					250			250		kΩ
Input Capacitance		Gain 2		2.0			2.0		pF	
Input Offset Current				0.4	3.0		0.4	5.0	μA	
Input Bias Current				9.0	20		9.0	30	μA	
Input Noise Voltage		BW = 1 kHz to 10 MHz		12			12		μVrms	
Input Voltage Range	1		±1.0			±1.0			V	
Common Mode Rejection Ratio										
Gain 2	1	V _{CM} = ±1V f ≤ 100 kHz	60	86		60	86		dB	
Gain 2		V _{CM} = ±1V f = 5 MHz		60			60		dB	
Supply Voltage Rejection Ratio										
Gain 2	1	ΔV _S = ±0.5V	50	70		50	70		dB	
Output Offset Voltage										
Gain 1	1	R _L = ∞		0.6	1.5		0.6	1.5	V	
Gain 2 and 3				0.35	1.0		0.35	1.5	V	
Output Common Mode Voltage	1	R _L = ∞	2.4	2.9	3.4	2.4	2.9	3.4	V	
Output Voltage Swing	1	R _L = 2k	3.0	4.0		3.0	4.0			
Output Sink Current			2.5	3.6		2.5	3.6		mA	
Output Resistance				20			20		Ω	
Power Supply Current	1	R _L = ∞		18	24		18	24	mA	

Electrical Characteristics (Continued)

(The following specifications apply for $-55^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$ for the LM733 and $0^{\circ}\text{C} < T_A < 70^{\circ}\text{C}$ for the LM733C, $V_S = \pm 6.0\text{V}$)

Characteristics	Test Circuit	Test Conditions	LM733			LM733C			Units
			Min	Typ	Max	Min	Typ	Max	
Differential Voltage Gain Gain 1 Gain 2 Gain 3	1	$R_L = 2\text{ k}\Omega, V_{OUT} = 3\text{ V}_{p-p}$	200 80 8.0		600 120 12.0	250 80 8.0	600 120 12.0		
Input Resistance Gain 2			8			8		$\text{k}\Omega$	
Input Offset Current					5		6	μA	
Input Bias Current					40		40	μA	
Input Voltage Range	1		± 1			± 1		V	
Common Mode Rejection Ratio Gain 2	1	$V_{CM} = \pm 1\text{ V } f \leq 100\text{ kHz}$	50			50		dB	
Supply Voltage Rejection Ratio Gain 2	1	$\Delta V_S = \pm 0.5\text{ V}$	50			50		dB	
Output Offset Voltage Gain 1 Gain 2 and 3	1	$R_L = \infty$			1.5 1.2		1.5 1.5	V V	
Output Voltage Swing	1	$R_L = 2\text{ k}$	2.5			2.8		V_{pp}	
Output Sink Current			2.2			2.5		mA	
Power Supply Current	1	$R_L = \infty$			27		27	mA	

Note 1: The maximum junction temperature of the LM733 is 150°C , while that of the LM733C is 100°C . For operation at elevated temperatures devices in the TO-100 package must be derated based on a thermal resistance of $150^{\circ}\text{C}/\text{W}$ junction to ambient or $45^{\circ}\text{C}/\text{W}$ junction to case. Thermal resistance of the dual-in-line package is $90^{\circ}\text{C}/\text{W}$.

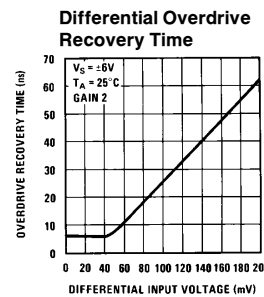
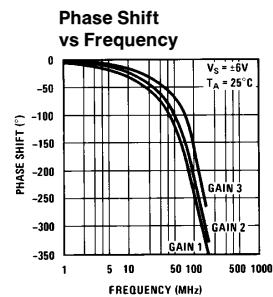
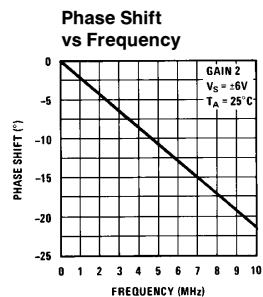
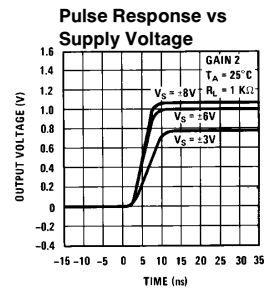
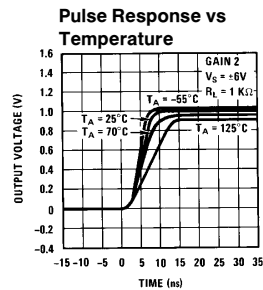
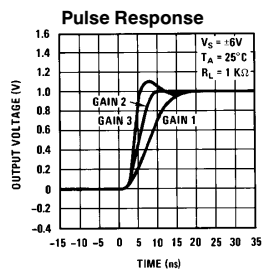
Note 2: Pins G1A and G1B connected together.

Note 3: Pins G2A and G2B connected together.

Note 4: Gain select pins open.

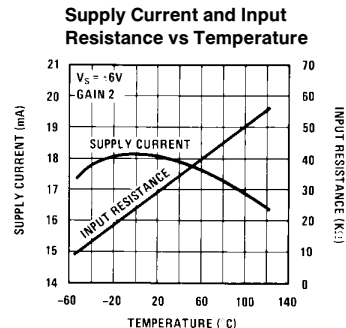
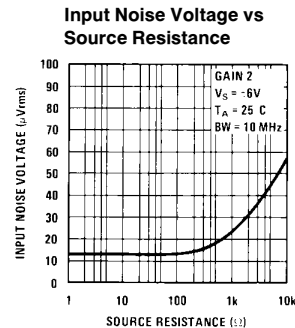
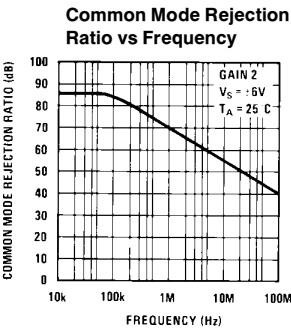
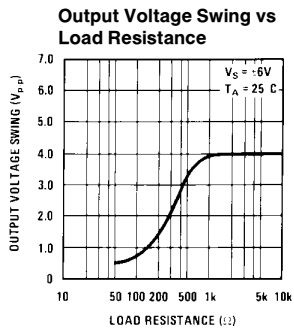
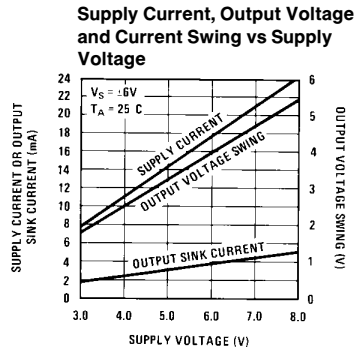
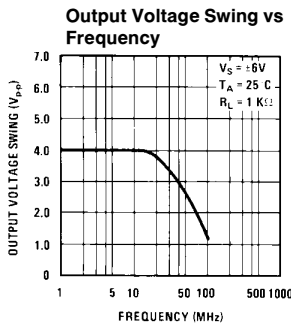
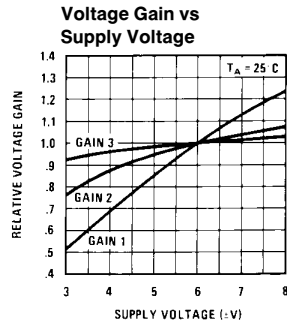
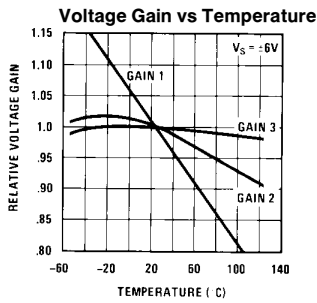
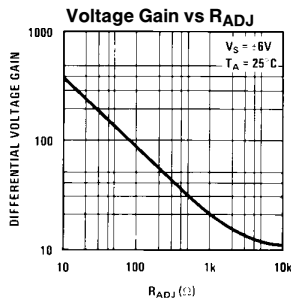
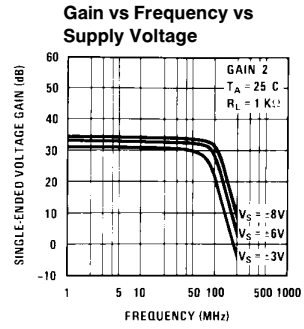
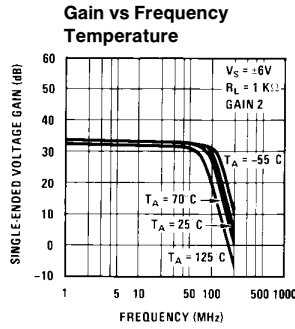
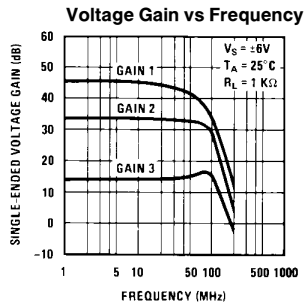
Note 5: Refer to RETS733X drawing for specifications of LM733H version.

Typical Performance Characteristics



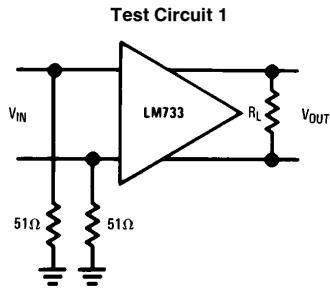
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Typical Performance Characteristics (Continued)

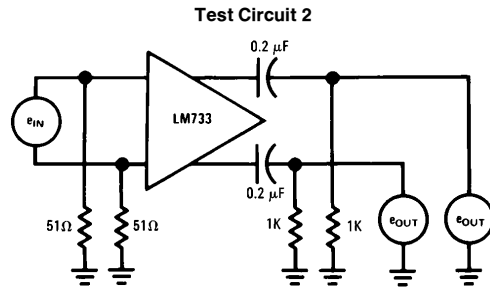


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Test Circuits

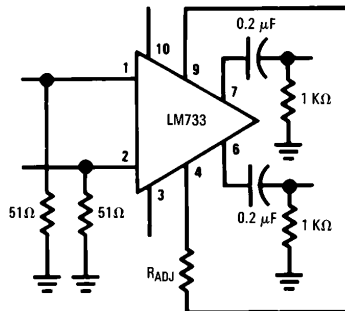


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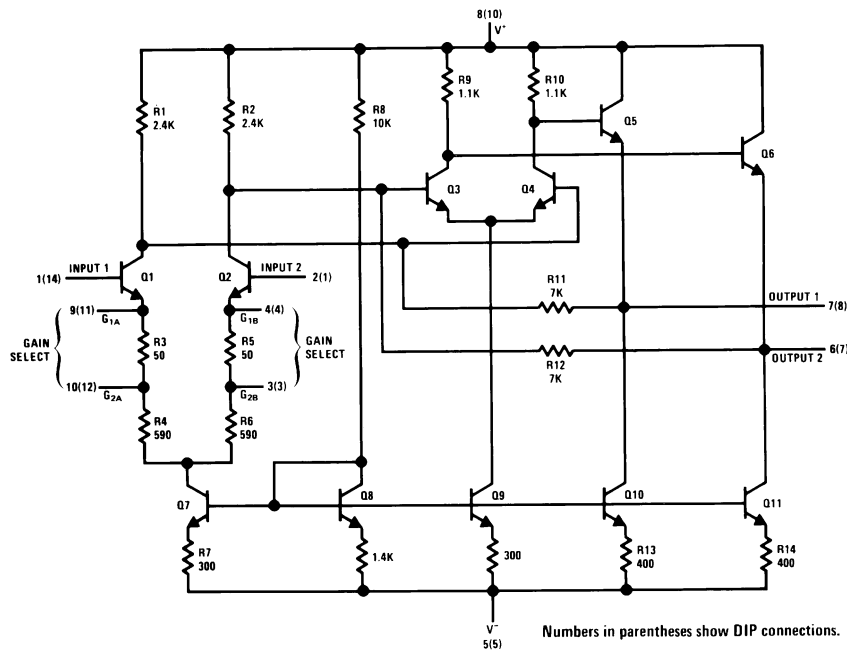
Voltage Gain Adjust Circuit



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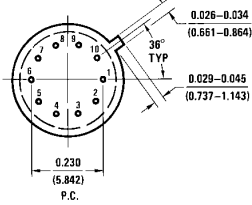
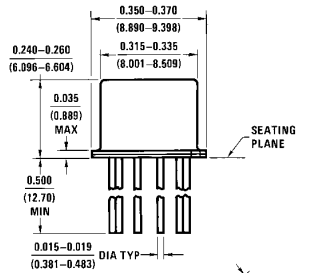
$V_S = 6V, T_A = 25^\circ C$
(Pin numbers apply to TO-5 package)

Schematic Diagram



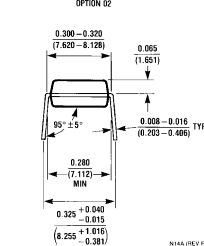
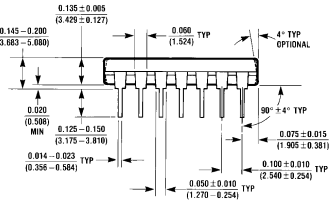
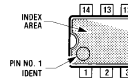
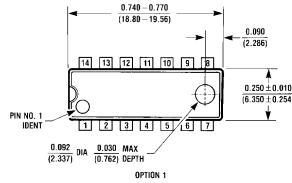
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Physical Dimensions inches (millimeters)



Metal Can Package (H)
Order Number LM733H or LM733CH
NS Package Number H10D

H10D (REV B)



N14A (REV F)

Molded Dual-In-Line Package (N)
Order Number LM733CN
NS Package Number N14A

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